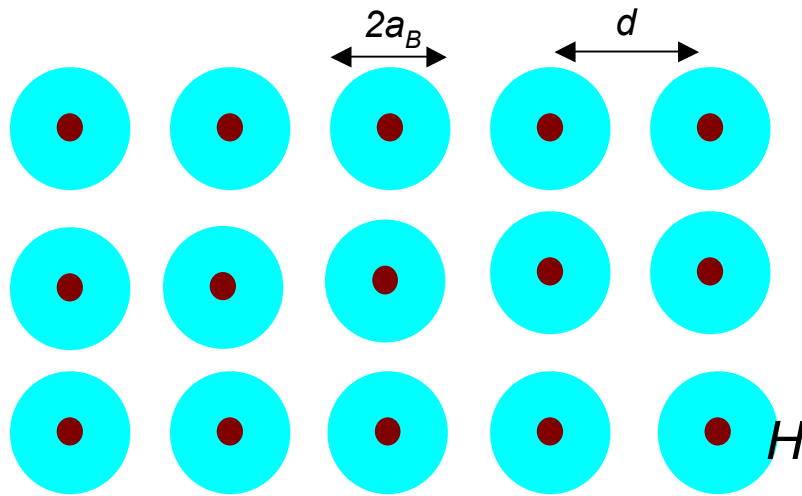


# Mott insulators

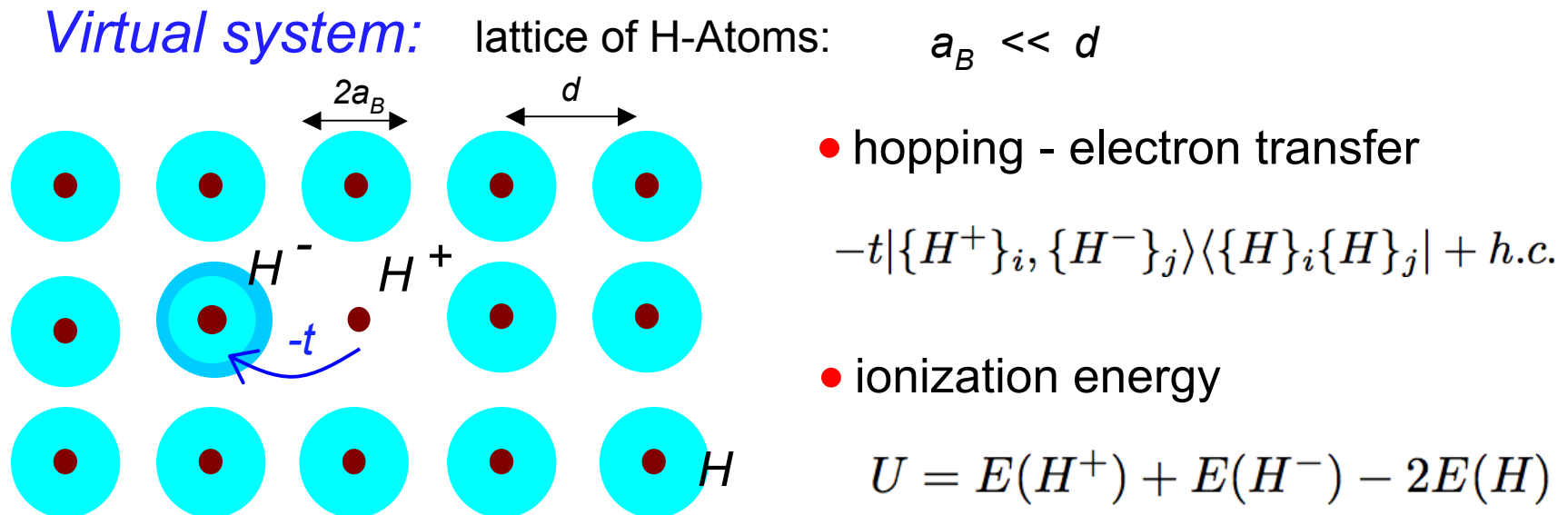
Atomic limit - view electrons in real space

*Virtual system:* lattice of H-Atoms:  $a_B \ll d$



# Mott insulators

Atomic limit - view electrons in real space



delocalization

$$-2tz$$

kinetic energy

*metal*



localization

$$U$$

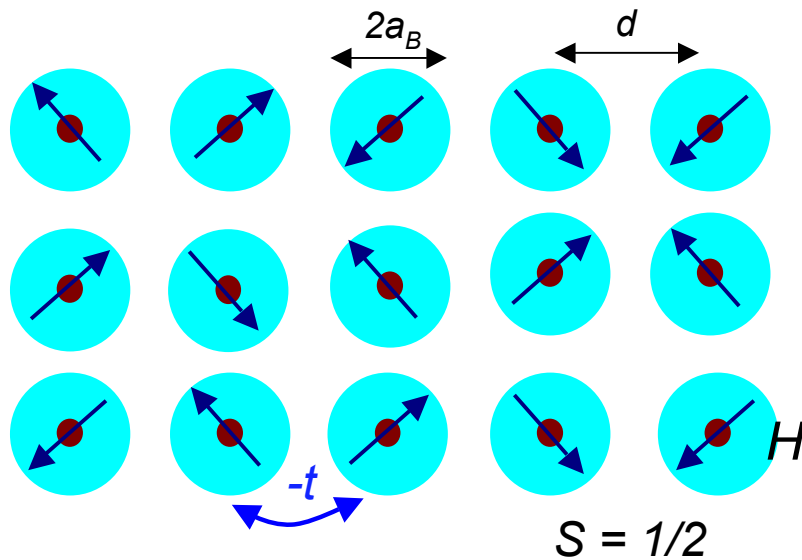
charge excitation energy

*Mott insulator*

# Mott insulators

## Atomic limit - view electrons in real space

*Virtual system:* lattice of H-Atoms:  $a_B \ll d$



- hopping - electron transfer

$$-t|\{H^+\}_i, \{H^-\}_j\rangle\langle\{H\}_i\{H\}_j| + h.c.$$

- ionization energy

$$U = E(H^+) + E(H^-) - 2E(H)$$

## Mott isolator

low-energy physics

no charge fluctuation

only spin fluctuation

effective low-energy model

$$H_{\text{Heisenberg}} = J \sum_{i,j} \vec{S}_i \cdot \vec{S}_j$$

# Mott insulators

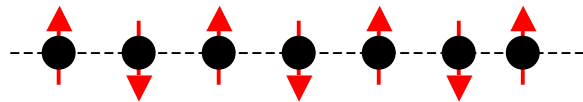
## Metal-insulator transition from the insulating side

Hubbard-model:

$$H = \underbrace{-t \sum_{\langle i,j \rangle, s} \{c_{is}^\dagger c_{js} + c_{js}^\dagger c_{is}\}}_{\text{n.n. hopping}} + \underbrace{U \sum_i n_{i\uparrow} n_{i\downarrow}}_{\text{onsite repulsion}} = \sum_{\vec{k}, s} \epsilon_{\vec{k}} c_{\vec{k}s}^\dagger c_{\vec{k}s} + U \sum_i n_{i\uparrow} n_{i\downarrow}$$

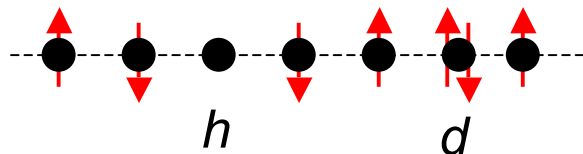
density:  $n=1$

„ground state“

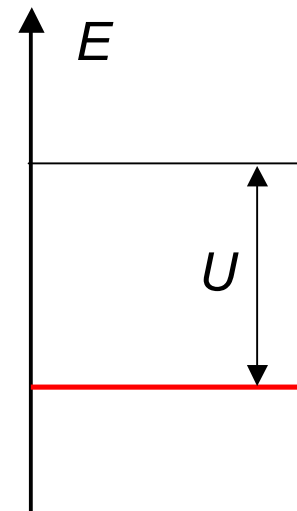


$$t = 0$$

charge excitation



$$E = U$$



# Mott insulators

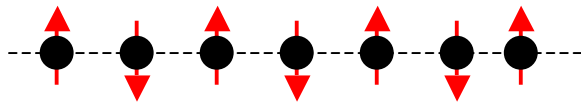
## Metal-insulator transition from the insulating side

Hubbard-model:

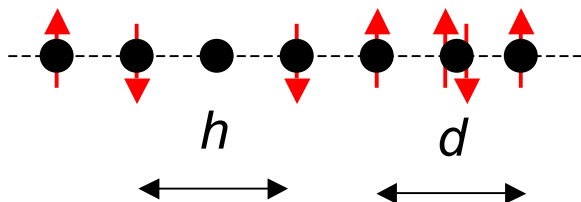
$$H = \underbrace{-t \sum_{\langle i,j \rangle, s} \{c_{is}^\dagger c_{js} + c_{js}^\dagger c_{is}\}}_{\text{n.n. hopping}} + \underbrace{U \sum_i n_{i\uparrow} n_{i\downarrow}}_{\text{onsite repulsion}} = \sum_{\vec{k}, s} \epsilon_{\vec{k}} c_{\vec{k}s}^\dagger c_{\vec{k}s} + U \sum_i n_{i\uparrow} n_{i\downarrow}$$

density:  $n=1$

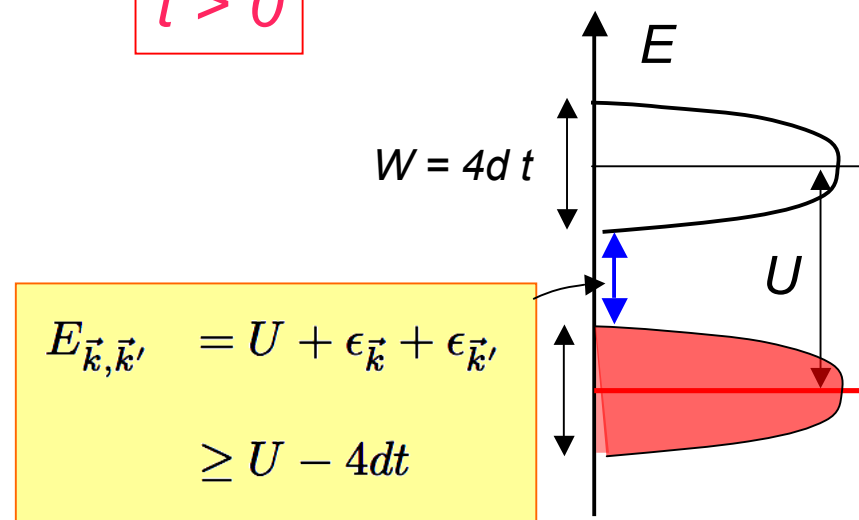
„ground state“



charge excitation



$$t > 0$$



metal-insulator transition:  $U_c = 4dt$

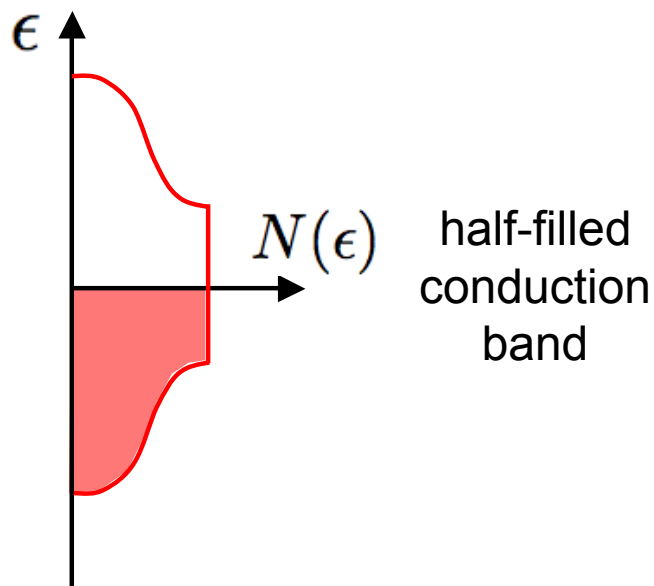
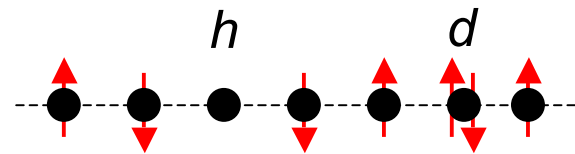
# Mott insulators

## Metal side

$$H = -t \sum_{\langle i,j \rangle, s} \{c_{is}^\dagger c_{js} + c_{js}^\dagger c_{is}\} + U \sum_i n_{i\uparrow} n_{i\downarrow} = \sum_{\vec{k}, s} \epsilon_{\vec{k}} c_{\vec{k}s}^\dagger c_{\vec{k}s} + U \sum_i n_{i\uparrow} n_{i\downarrow}$$

$$\epsilon_{\vec{k}} = -2t(\cos k_x a + \cos k_y a + \cos k_z a)$$

$U = 0$  tight-binding model



empty sites  $h = 1/4$   
 doubly occupied sites  $d = 1/4$   
 singly occupied sites  $s = 1/2$

$U > 0 \rightarrow \begin{cases} h = d \rightarrow 0 \\ s \rightarrow 1 \end{cases}$

reducing mobility

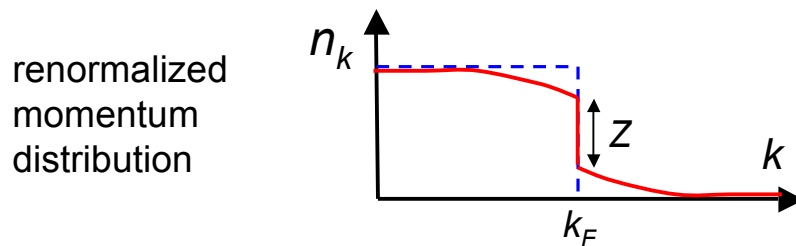
# Mott insulators

## Metal-insulator transition from the metallic side

Gutzwiller approximation

$$\mathcal{H}_{eff} = g_t \sum_{\vec{k}, s} \epsilon_{\vec{k}} c_{\vec{k}s}^\dagger c_{\vec{k}s} \quad g_t = 1 - \left( \frac{U}{U_c} \right)^2$$

### Fermi liquid property



quasiparticle weight:  $Z = g_t$

at MIT  $U \rightarrow U_c$

$$\left\{ \begin{array}{l} \frac{m^*}{m} \rightarrow \infty \\ Z \rightarrow 0 \end{array} \right.$$

### single particle spectral function

